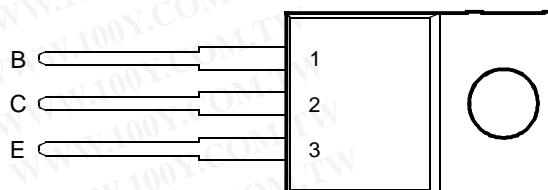


- Rugged Triple-Diffused Planar Construction
- 4 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- 1000 Volt Blocking Capability
- 75 W at 25°C Case Temperature

TO-220 PACKAGE  
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRACA

**absolute maximum ratings at 25°C case temperature (unless otherwise noted)**

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	TIPL760 TIPL760A	$V_{CBO}$	850 1000	V
Collector-emitter voltage ( $V_{BE} = 0$ )	TIPL760 TIPL760A	$V_{CES}$	850 1000	V
Collector-emitter voltage ( $I_B = 0$ )	TIPL760 TIPL760A	$V_{CEO}$	400 450	V
Emitter-base voltage		$V_{EBO}$	10	V
Continuous collector current		$I_C$	4	A
Peak collector current (see Note 1)		$I_{CM}$	8	A
Continuous device dissipation at (or below) 25°C case temperature		$P_{tot}$	75	W
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C

NOTE 1: This value applies for  $t_p \leq 10$  ms, duty cycle  $\leq 2\%$ .

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**PRODUCT INFORMATION**

Information is current as of publication date. Products conform to specifications in accordance with the terms of Power Innovations standard warranty. Production processing does not necessarily include testing of all parameters.

# TIPL760, TIPL760A NPN SILICON POWER TRANSISTORS

AUGUST 1978 - REVISED MARCH 1997

## electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS				MIN	TYP	MAX	UNIT
$V_{CEO(sus)}$	$I_C = 10 \text{ mA}$	$L = 25 \text{ mH}$	(see Note 2)	TIPL760 TIPL760A	400 450			V
$I_{CES}$	$V_{CE} = 850 \text{ V}$ $V_{CE} = 1000 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$		TIPL760 TIPL760A			50 50	$\mu\text{A}$
$I_{CEO}$	$V_{CE} = 850 \text{ V}$ $V_{CE} = 1000 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$	$T_C = 100^\circ\text{C}$ $T_C = 100^\circ\text{C}$	TIPL760 TIPL760A			200 200	$\mu\text{A}$
$I_{EBO}$	$V_{CE} = 400 \text{ V}$ $V_{CE} = 450 \text{ V}$	$I_B = 0$ $I_B = 0$		TIPL760 TIPL760A			50 50	$\mu\text{A}$
$h_{FE}$	$V_{CE} = 5 \text{ V}$	$I_C = 0.5 \text{ A}$	(see Notes 3 and 4)		20		60	
$V_{CE(sat)}$	$I_B = 0.5 \text{ A}$ $I_B = 0.8 \text{ A}$ $I_B = 0.8 \text{ A}$	$I_C = 2.5 \text{ A}$ $I_C = 4 \text{ A}$ $I_C = 4 \text{ A}$					1.0 2.5 5.0	V
$V_{BE(sat)}$	$I_B = 0.5 \text{ A}$ $I_B = 0.8 \text{ A}$ $I_B = 0.8 \text{ A}$	$I_C = 2.5 \text{ A}$ $I_C = 4 \text{ A}$ $I_C = 4 \text{ A}$	(see Notes 3 and 4) $T_C = 100^\circ\text{C}$				1.2 1.4 1.3	V
$f_t$	$V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ MHz}$			12		MHz
$C_{ob}$	$V_{CB} = 20 \text{ V}$	$I_E = 0$	$f = 0.1 \text{ MHz}$			110		pF

NOTES: 2. Inductive loop switching measurement.

3. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

## thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.56	°C/W

## inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>†</sup>				MIN	TYP	MAX	UNIT
$t_{sv}$	$I_C = 4 \text{ A}$						2.5	$\mu\text{s}$
$t_{rv}$	$V_{BE(off)} = -5 \text{ V}$	$I_{B(on)} = 0.8 \text{ A}$	(see Figures 1 and 2)				300	ns
$t_{fi}$							250	ns
$t_{ti}$							150	ns
$t_{xo}$							400	ns
$t_{sv}$	$I_C = 4 \text{ A}$						3	$\mu\text{s}$
$t_{rv}$	$V_{BE(off)} = -5 \text{ V}$	$I_{B(on)} = 0.8 \text{ A}$	(see Figures 1 and 2)				500	ns
$t_{fi}$							250	ns
$t_{ti}$							150	ns
$t_{xo}$	$T_C = 100^\circ\text{C}$						750	ns

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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## PRODUCT INFORMATION

### PARAMETER MEASUREMENT INFORMATION

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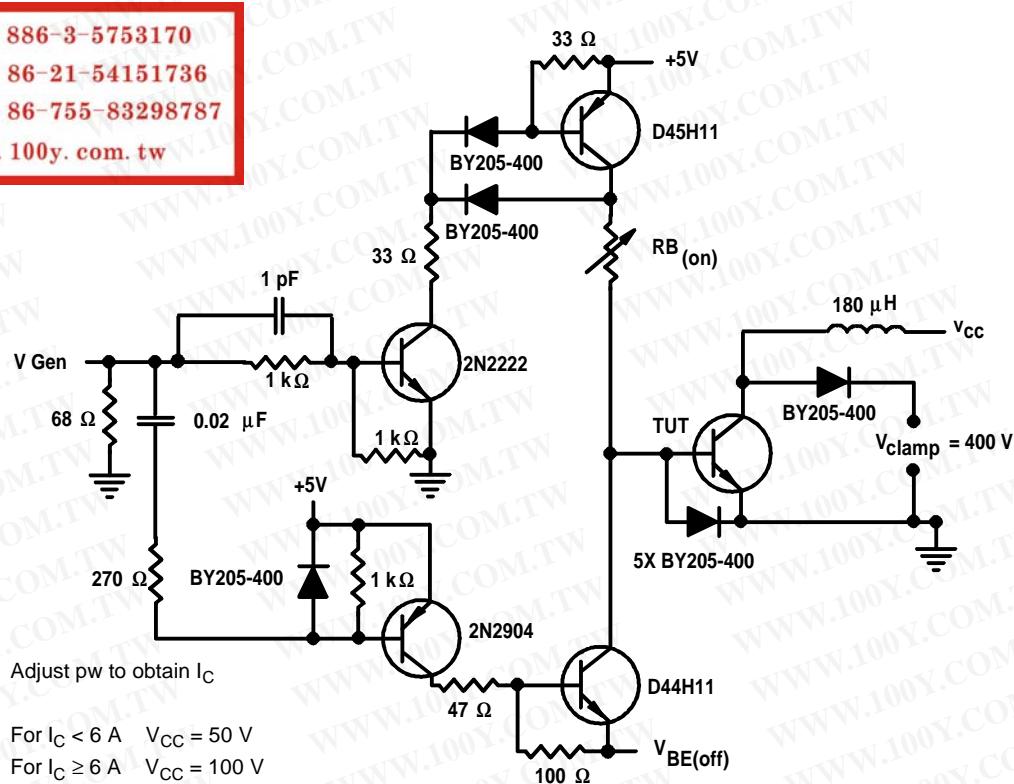
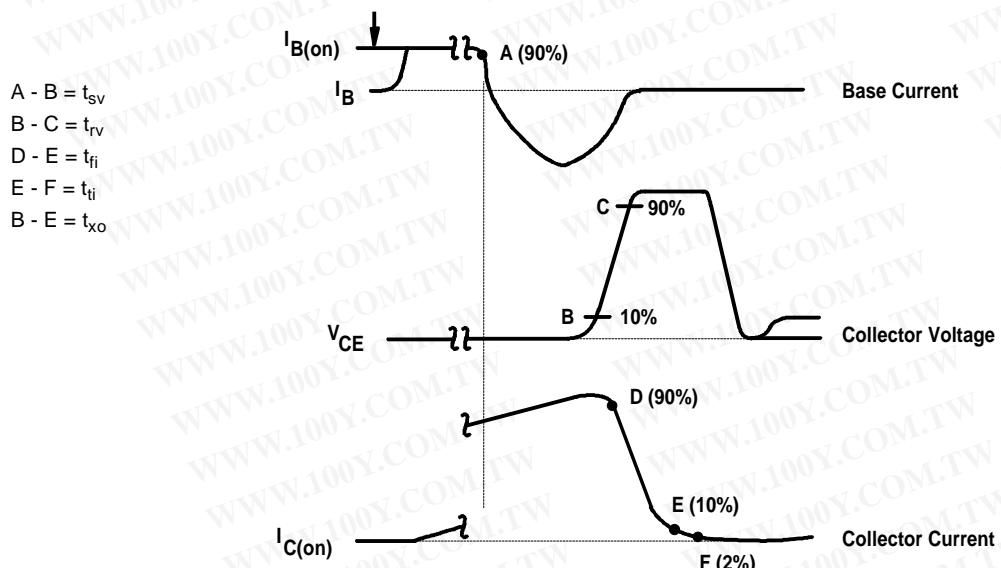


Figure 1. Inductive-Load Switching Test Circuit



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics:  $t_r < 15$  ns,  $R_{in} > 10 \Omega$ ,  $C_{in} < 11.5$  pF.  
B. Resistors must be noninductive types.

Figure 2. Inductive-Load Switching Waveforms

# TIPL760, TIPL760A NPN SILICON POWER TRANSISTORS

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## TYPICAL CHARACTERISTICS

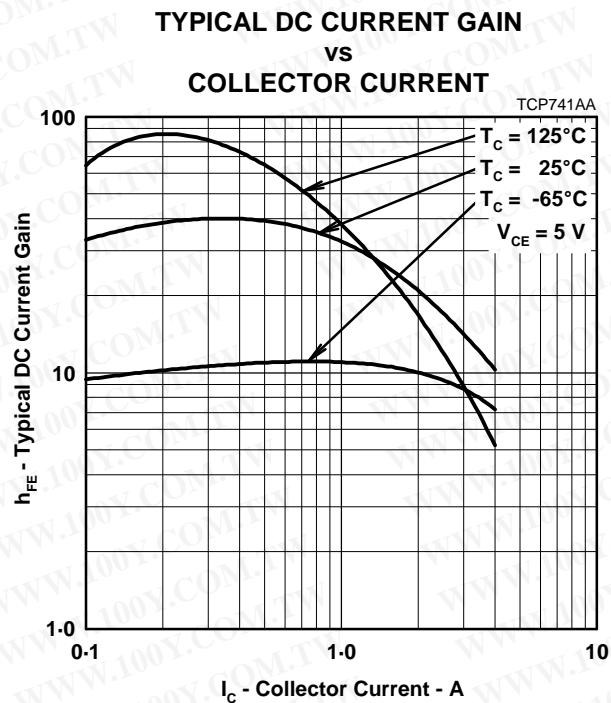


Figure 3.

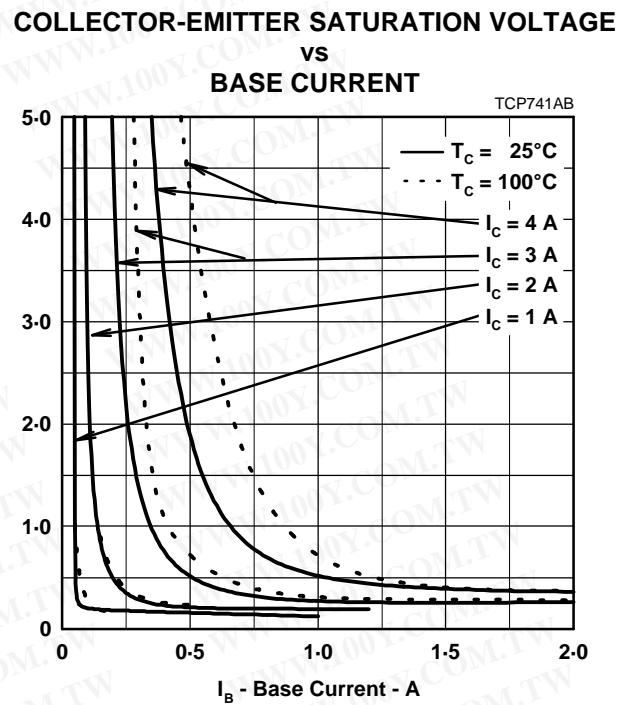


Figure 4.

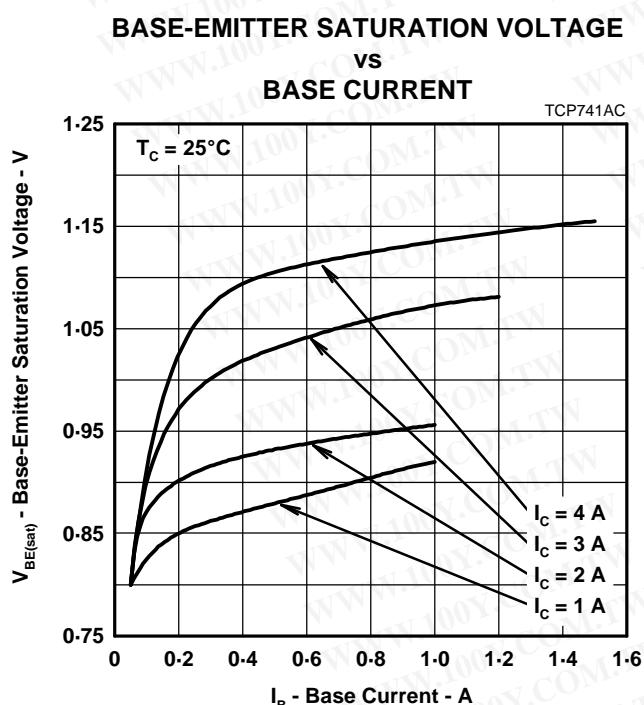


Figure 5.

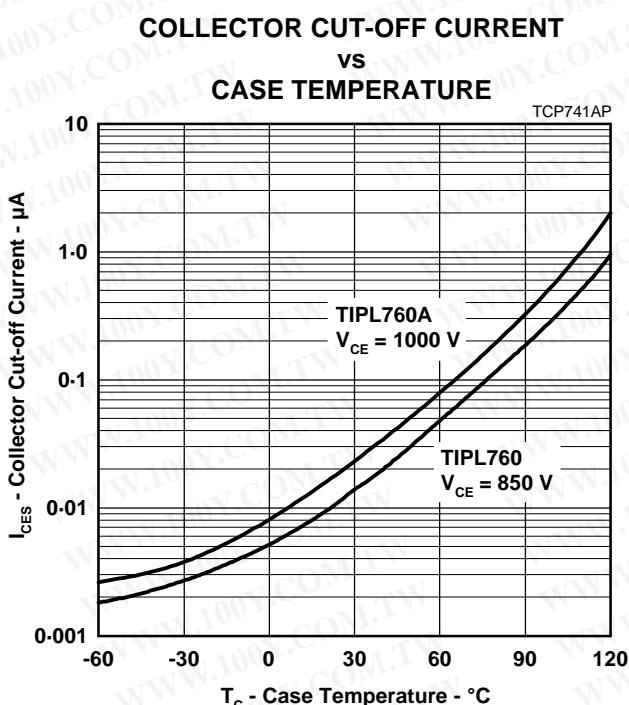


Figure 6.

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## MAXIMUM SAFE OPERATING REGIONS

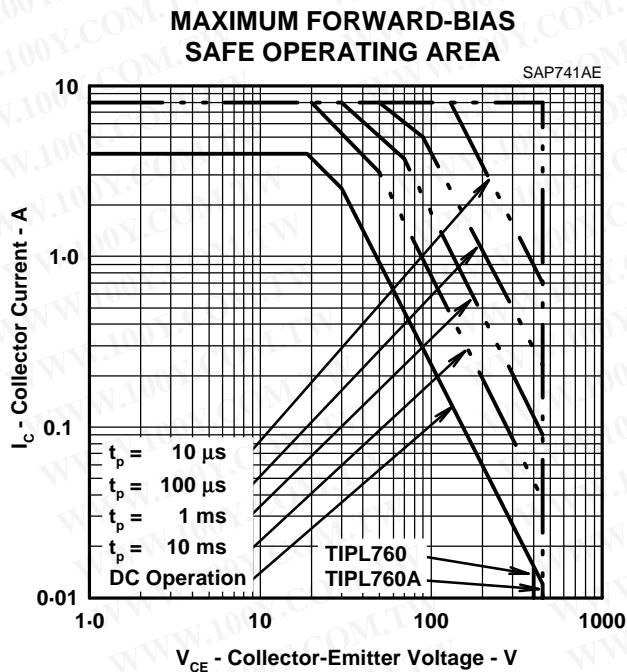


Figure 7.

## THERMAL INFORMATION

### THERMAL RESPONSE JUNCTION TO CASE VS POWER PULSE DURATION

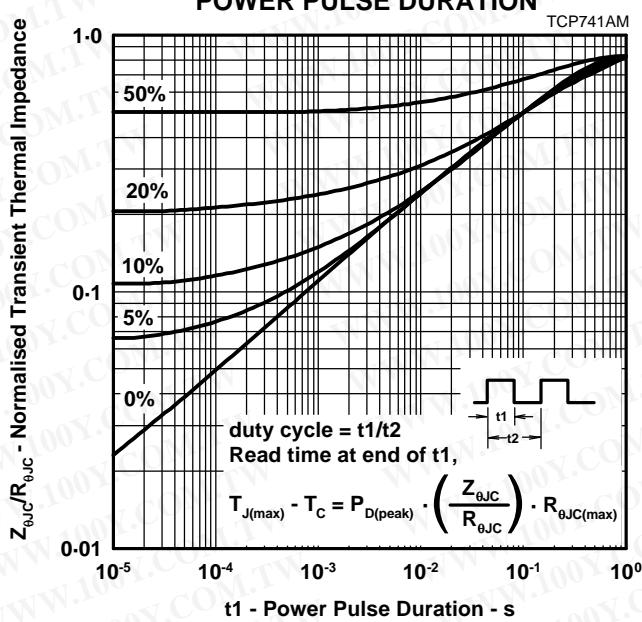


Figure 8.

# TIPL760, TIPL760A NPN SILICON POWER TRANSISTORS

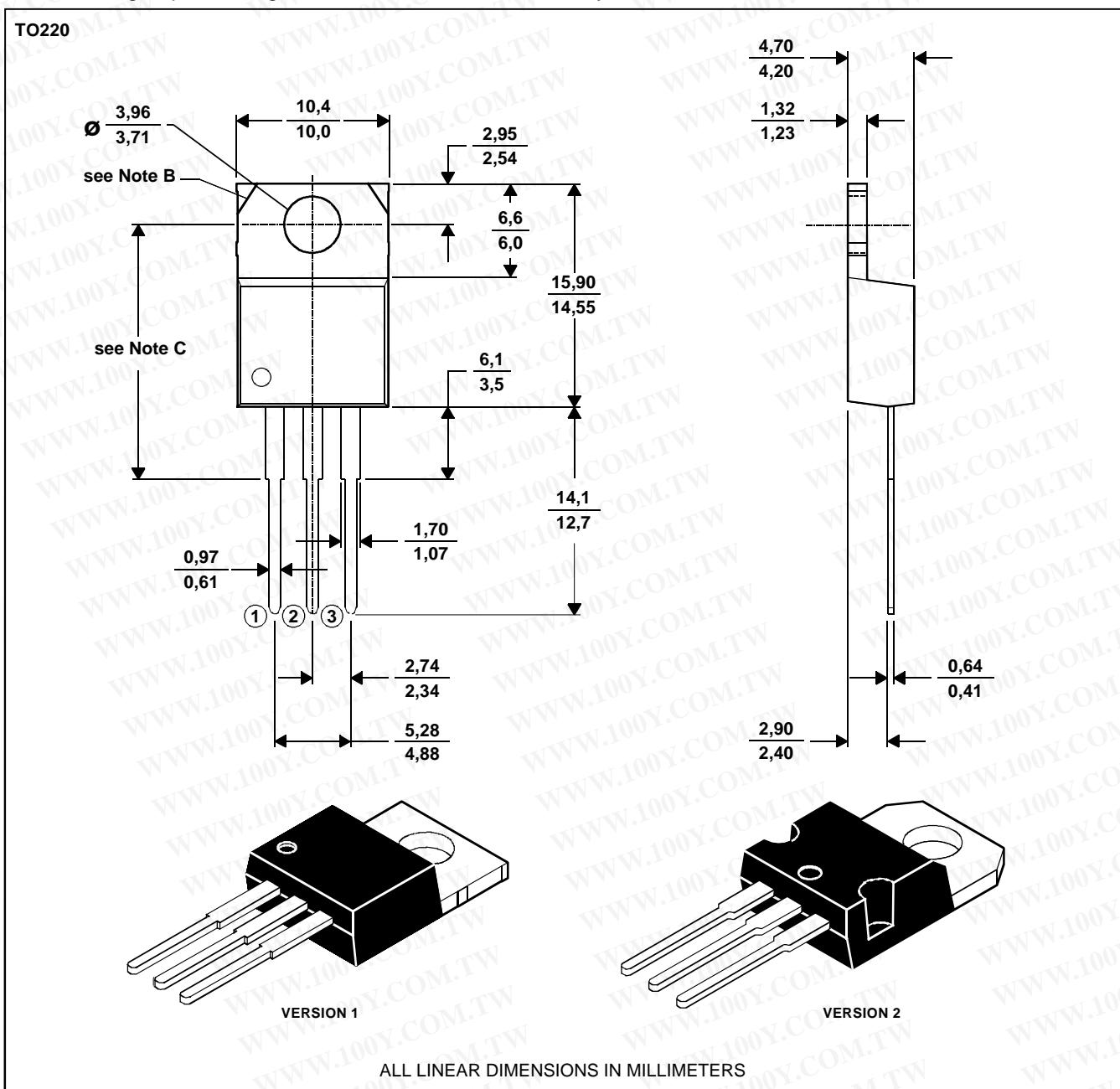
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## MECHANICAL DATA

### TO-220

#### 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.  
B. Mounting tab corner profile according to package version.  
C. Typical fixing hole centre stand off height according to package version.  
Version 1, 18.0 mm. Version 2, 17.6 mm.

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